Ref #	Hits	Search Query	DBs	Default Operato r	Plural s	Time Stamp
L1	3449	high adj density with layer and planariz\$3 with layer	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:52
L2	22	1 and organic adj optoelectronic	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:53
L3	12	1 and organic adj optoelectronic and surround	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:47
L5	3640	313/504.ccls.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:51
L6	3623	313/506.ccls.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:51

L7	1273	313/512.ccls.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T;	OR	ON	2006/10/29 19:52
L8	3281	428/690.ccls.	IBM_TDB US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:52
L9	2554	257/99.ccls.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:52
L10	952	257/100.ccls.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:52
L11	2337	257/40.ccls.	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:52

L12	18	5 and high adj density with layer and planariz\$3 with layer	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:52
L13	15	6 and high adj density with layer and planariz\$3 with layer	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:53
L14	12	7 and high adj density with layer and planariz\$3 with layer	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:53
L15	5	8 and high adj density with layer and planariz\$3 with layer	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON ·	2006/10/29 19:53
L16	6	9 and high adj density with layer and planariz\$3 with layer	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:53

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L17	8	10 and high adj density with	US-PGPU	OR	ON	2006/10/29
517	J	layer and planariz\$3 with layer	B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB		OIN	19:53
L18	10	11 and high adj density with layer and planariz\$3 with layer	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:53
L19	11	12 and organic adj optoelectronic	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:53
L20	10	13 and organic adj optoelectronic	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:53
L21	5	14 and organic adj optoelectronic	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:53

L22	4	15 and organic adj optoelectronic	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:53
L23	3	16 and organic adj optoelectronic	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:54
L24	4	17 and organic adj optoelectronic	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:54
L25	2	18 and organic adj optoelectronic	US-PGPU B; USPAT; USOCR; FPRS; EPO; JPO; DERWEN T; IBM_TDB	OR	ON	2006/10/29 19:54